

General Purpose Transistor (-50V, -0.15A)

2SA1037AK / 2SA1576A / 2SA1774 / 2SA2029

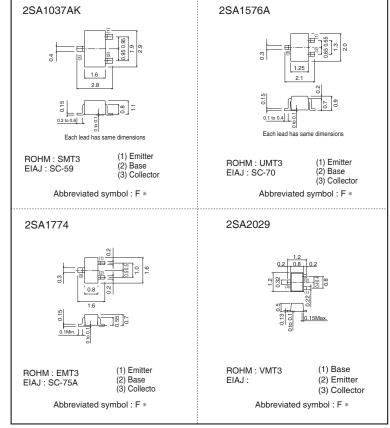
Features

- 1) Excellent hee linearity.
- 2) Complements the 2SC2412K / 2SC4081 / 2SC4617 / 2SC5658.

Structure

Epitaxial planar type. PNP silicon transistor

•Dimensions (Unit : mm)



* Denotes hre

•Absolute maximum ratings (Ta=25°C)

Parameter		Symbol	Limits	Unit
Collector-base voltage		Vсво	-60	V
Collector-emitter voltage		VCEO	-50	V
Emitter-base voltage		Vево	-6	V
Collector current		lc	-0.15	A (DC)
Collector power dissipation	2SA1037AK, 2SA1576A	5	0.2	w
	2SA2029, 2SA1774	Pc	0.15	
Junction temperature		Tj	150	°C
Storage temperature		Tstg	-55 to +150	°C

•Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Collector-base breakdown voltage	ВУсво	-60	-	-	V	Ic=-50μA
Collector-emitter breakdown voltage	BVCEO	-50	-	-	V	Ic=-1mA
Emitter-base breakdown voltage	ВУево	-6	_	_	V	Iε= -50μA
Collector cutoff current	Ісво	_	-	-0.1	μΑ	Vсв=-60V
Emitter cutoff current	Іево	-	-	-0.1	μΑ	Veb=-6V
Collector-emitter saturation voltage	VCE(sat)	_	_	-0.5	V	Ic/I _B = -50mA/-5mA
DC current transfer ratio	hfe	120	_	390	_	Vce=-6V, Ic=-1mA
Transition frequency	f⊤	_	140	_	MHz	Vce=-12V, Ie=2mA, f=100MHz
Output capacitance	Cob	_	4.0	5.0	pF	Vcb=-12V, Ie=0A, f=1MHz

•Packaging specifications and hre

		Package			Taping	
		Code	T146	T106	TL	T2L
Туре	hfe	Basic ordering unit (pieces)	3000	3000	3000	8000
2SA2029	QR		-	-	_	0
2SA1037AK	QR		0	_	_	-
2SA1576A	QR		-	0	_	-
2SA1774	QR		_	_	0	_

hFE values are classified as follows:

Item	Q	R
hfe	120 to 270	180 to 390

•Electrical characteristic curves -50 VCE=-6V 100°C COLLECTOR CURRENT : Ic (mA) -20 25 40 -10 -2 -0.5 -0.2 -0. 0.2 -0.6 -0.8 -1.0 -1.2 -1.4 -0.4 -1.6BASE TO EMITTER VOLTAGE : VBE (V) Fig.1 Grounded emitter propagation characteristics 500 Ta=25°C -5V -3V -1V Щ DC CURRENT GAIN : 200 100 50 -0.2 -0.5 -1 -2 -5 -10 -20 -50 -100 COLLECTOR CURRENT : Ic (mA) Fig.4 DC current gain vs. collector current (I) Ic/le=10 VCE(sat) (V) -0 COLLECTOR SATURATION VOLTAGE : -0.2 100°C 25°C -0. ΗT -0.05 ТП -0.2 -0.5 -1 -2 -5 -10 -20 -50 -100 COLLECTOR CURRENT : Ic (mA) Fig.7 Collector-emitter saturation voltage vs. collector current (II)

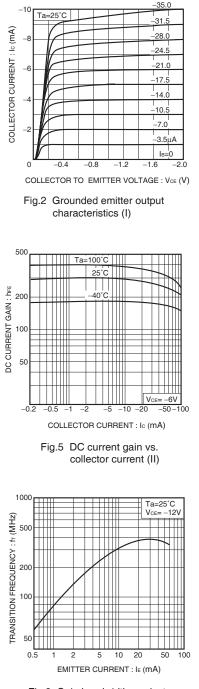
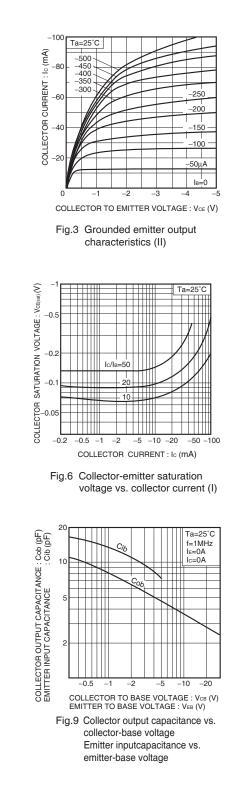


Fig.8 Gain bandwidth product vs. emitter current



	Notes
	or reproduction of this document, in part or in whole, is permitted without the OHM Co.,Ltd.
The content	specified herein is subject to change for improvement without notice.
"Products").	specified herein is for the purpose of introducing ROHM's products (hereinafter If you wish to use any such Product, please be sure to refer to the specifications e obtained from ROHM upon request.
illustrate the	application circuits, circuit constants and any other information contained hereir standard usage and operations of the Products. The peripheral conditions must b account when designing circuits for mass production.
However, sh	vas taken in ensuring the accuracy of the information specified in this document nould you incur any damage arising from any inaccuracy or misprint of such ROHM shall bear no responsibility for such damage.
examples of implicitly, an other parties	al information specified herein is intended only to show the typical functions of and f application circuits for the Products. ROHM does not grant you, explicitly of y license to use or exercise intellectual property or other rights held by ROHM and s. ROHM shall bear no responsibility whatsoever for any dispute arising from the technical information.
equipment o	is specified in this document are intended to be used with general-use electronic or devices (such as audio visual equipment, office-automation equipment, commu- ices, electronic appliances and amusement devices).
The Product	s specified in this document are not designed to be radiation tolerant.
	I always makes efforts to enhance the quality and reliability of its Products, a fail or malfunction for a variety of reasons.
against the p failure of any shall bear no	ure to implement in your equipment using the Products safety measures to guard possibility of physical injury, fire or any other damage caused in the event of the / Product, such as derating, redundancy, fire control and fail-safe designs. ROHM o responsibility whatsoever for your use of any Product outside of the prescribed in accordance with the instruction manual.
system whic may result ir instrument, t controller or of the Produ	ts are not designed or manufactured to be used with any equipment, device of the requires an extremely high level of reliability the failure or malfunction of which in a direct threat to human life or create a risk of human injury (such as a medica transportation equipment, aerospace machinery, nuclear-reactor controller, fuel- other safety device). ROHM shall bear no responsibility in any way for use of any ucts for the above special purposes. If a Product is intended to be used for any purpose, please contact a ROHM sales representative before purchasing.
be controlled	I to export or ship overseas any Product or technology specified herein that may d under the Foreign Exchange and the Foreign Trade Law, you will be required to nse or permit under the Law.



Thank you for your accessing to ROHM product informations. More detail product informations and catalogs are available, please contact us.

ROHM Customer Support System

http://www.rohm.com/contact/

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

ROHM Semiconductor:

<u>2SA1037AKT146Q</u> <u>2SA1037AKT146R</u> <u>2SA1037AKT146S</u> <u>2SA1576AT106Q</u> <u>2SA1576AT106R</u> <u>2SA1576AT106R</u> <u>2SA1576AT106S</u> <u>2SA1774TLQ</u> <u>2SA1774TLR</u> <u>2SA1774TLS</u> <u>2SA2029FST2LQ</u> <u>2SA2029T2LQ</u> <u>2SA933ASTPQ</u> <u>2SA933ASTPR</u> <u>2SA933ASTPS</u> <u>2SA2029T2LR</u>